



Time: 1 hour and 30 minutes

EXERCISE 1

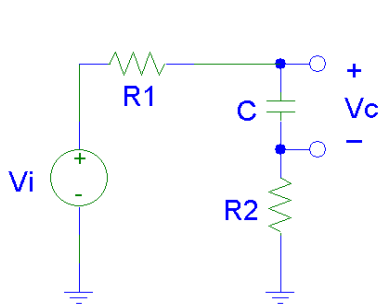


Figure 1a

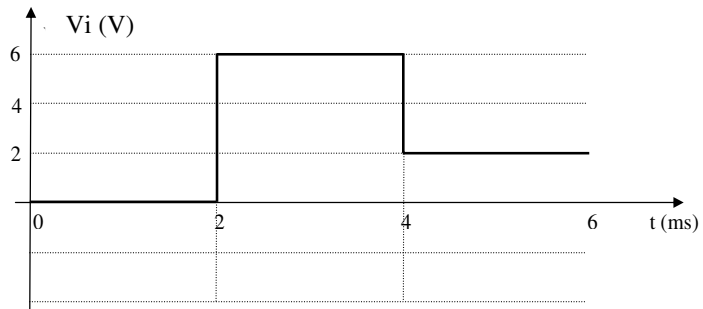
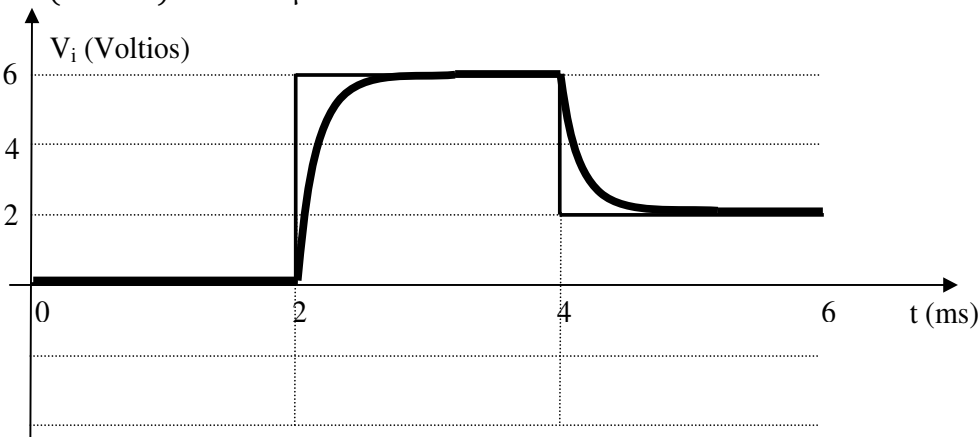


Figure 1b

DATA:  $R1 = 1\text{ k}\Omega$   $C = 100\text{ nF}$   $R2 = 1\text{ k}\Omega$

a)  $\tau = (R1+R2) \cdot C = 200\text{ }\mu\text{s} \ll 1\text{ ms}$



b)  $Vc(2\text{ms}) = 0\text{V}$

$Vc(2.2\text{ms}) = 63\% \cdot 6\text{V} = 0.63 \cdot 6\text{V}$  ( $t = 1\tau$ )

$Vc(3\text{ms}) = 6\text{V}$  ( $t = 5\tau$ )

$Vc(4\text{ms}) = 6\text{V}$

$Vc(5\text{ms}) = 2\text{V}$  ( $t = 5\tau$ )



## EXERCISE 2

In the circuit of Figure 2,  $V_g$  is a sinusoidal voltage source whose amplitude is set to 1 V peak. The frequency can be changed.  $R = 1\text{K}\Omega$ ,  $C = 100\text{nF}$ .

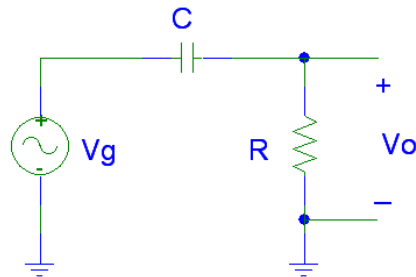


Figure 2

a)  $V_o$

$$V_o = V_g \frac{j\omega CR}{1 + j\omega CR}$$

b)  $\omega = 1/(R \cdot C)$

$$|V_o| = |V_g| \left| \frac{j}{1 + j} \right| = \frac{|V_g|}{\sqrt{2}}$$

$$|V_o| = 1/\sqrt{2} \text{ V peak}$$

c)  $\omega = 10/(R \cdot C)$ .

$$\phi_{V_o} - \phi_{V_g} = -\text{arctg}(-1/10) = 5.7^\circ$$

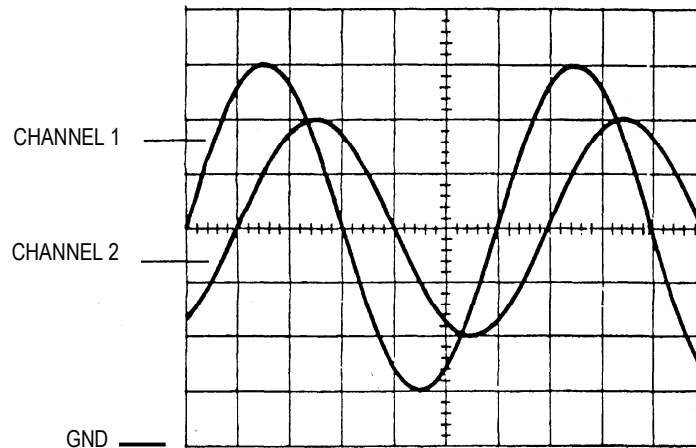
d)  $f \rightarrow 0 \Rightarrow V_o = 0 \text{ V}$

$$f \rightarrow \infty \Rightarrow V_o \approx V_g$$



### EXERCISE 3

The signals in Figure 3 are observed in an oscilloscope with the following adjustments:  
 $10\mu\text{s}/\text{Div}$ ,  $200\text{ mV}/\text{Div}$ .



**Figure 3**

- a)  $T = 60\ \mu\text{s}$        $f = 1/60\ \text{MHz}$        $V1 = 600\ \text{mV pk}$        $V2 = 400\ \text{mV pk}$
- b)  $t = 10\ \mu\text{s}$        $\phi = 60^\circ$        $\phi = \pi/3\ \text{rad}$
- c)  $V1(\text{DC}) = 800\ \text{mV}$
- d)  $V1(\text{AC}) = 600 / \sqrt{2}\ \text{mV (rms)}$

### EXERCISE 4

We want to fabricate a resistor with the following characteristics: nominal value  $2.2\text{K}\Omega$  and dissipation up to  $1/4\text{W}$ . A resistive film is used:

Film resistance:  $300\Omega/\square$       Maximum dissipation:  $1\text{W}/\text{cm}^2$

- a)  $L/W = 7.33\ \square$        $W = 1.85\ \text{mm}$        $L = 13.54\ \text{mm}$

Information of the datasheet: Resistance  $2\text{K}2$  (room temperature of  $25^\circ\text{C}$ ) and temperature coefficient  $10^{-4}\ \Omega/(\Omega\cdot^\circ\text{C})$

- b)  $R(125^\circ) = 2.2\text{K} \cdot (1+0.01) = 2.222\ \text{K}\Omega$
- c)  $R'(125^\circ) = 22\text{K} \cdot (1+0.01) = 22.22\ \text{K}\Omega$
- d)  $R = 2.2\text{K} (1\pm 0.1)$       Min  $1.98\ \text{K}\Omega$       Max  $2.42\ \text{K}\Omega$



EXERCISE 5

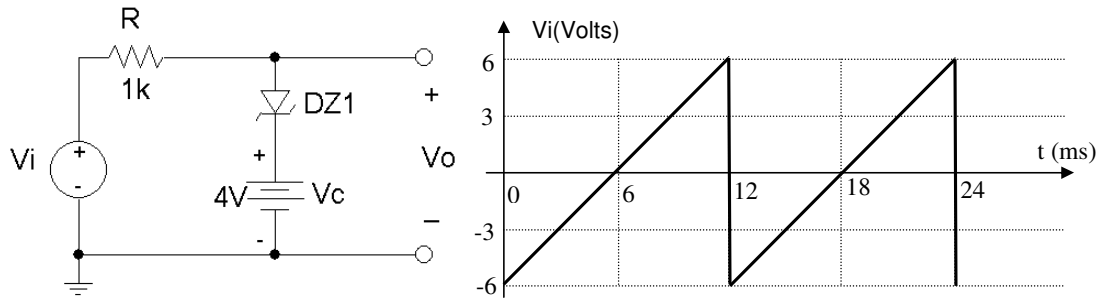
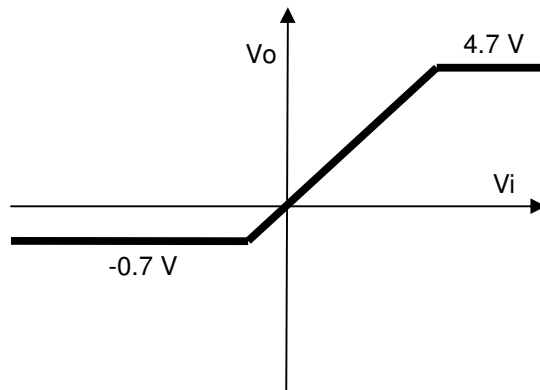


Figure 4a

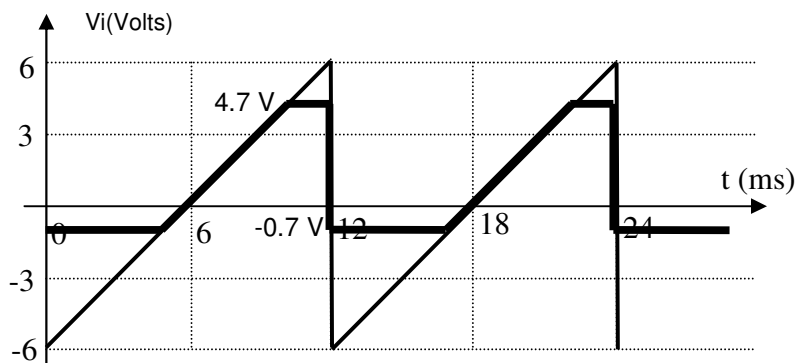
Figure 4b

DATA (zener diode): ZENNER voltage:  $V_z = 4.7 \text{ V}$  ON voltage:  $V_D = 0.7 \text{ V}$

a) Transfer function

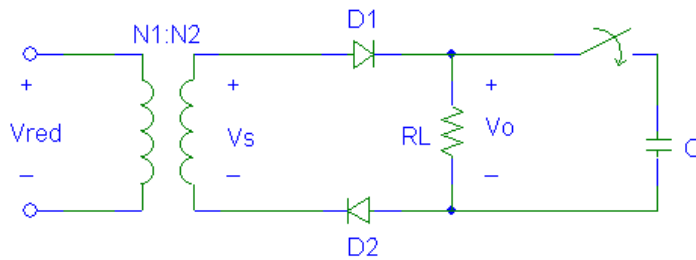


b) Output voltage  $V_o$



EXERCISE 6

The scheme of the Figure 5 is an application circuit with diodes.  $V_{red}$  is the accessible voltage one can find in an electric plug at home.



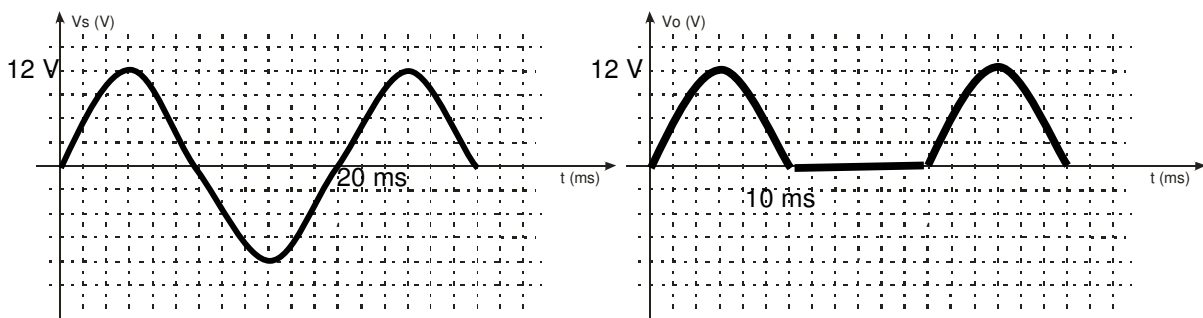
**DATA:**

$V_{red} = 220 \text{ Vrms}; 50 \text{ Hz}$   
 $N1/N2=26$   
 Ideal diodes ( $V_{D-ON} = 0\text{V}$ )  
 $R_L = 300 \Omega$

**Figure 5**

a) AC to DC conversion: Half-wave rectifier

b)  $V_s$  and  $V_o$



c) Value of C so as the ripple is less than 1Vpp.

$$C = (T/RL) \cdot (V_p/V_r) = 800 \mu\text{F}$$